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# P-Channel 30 V (D-S) 175 °C MOSFET

#### **DESCRIPTION**

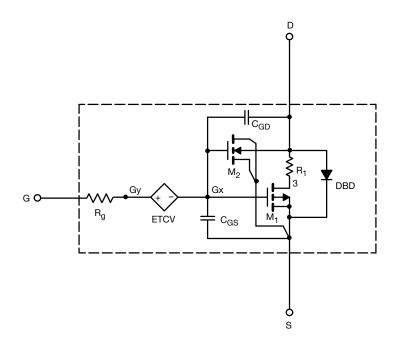
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55  $^{\circ}\text{C}$  to +125  $^{\circ}\text{C}$  temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- · Model the Gate Charge

#### SUBCIRCUIT MODEL SCHEMATIC



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# SPICE Device Model SQM50P03-07

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SPECIFICATIONS (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	2	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, I_D = -30 \text{ A}$	0.0053	0.0050	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -20 \text{ A}$	0.0097	0.0089	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = -15 V, I <sub>D</sub> = -30 A	62	62	S
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = -45 A	-0.9	-0.9	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	4340	4304	pF
Output Capacitance	Coss		766	764	
Reverse Transfer Capacitance	C <sub>rss</sub>		682	680	
Total Gate Charge	$Q_g$	V <sub>DS</sub> = -15 V, V <sub>GS</sub> = -10 V, I <sub>D</sub> = -75 A	98	103.5	nC
Gate-Source Charge	Q <sub>gs</sub>		14.3	14.3	
Gate-Drain Charge	$Q_{gd}$		26.9	26.9	

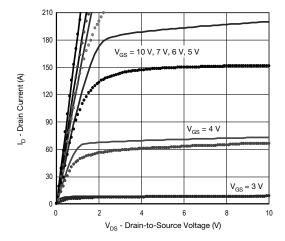
#### Notes

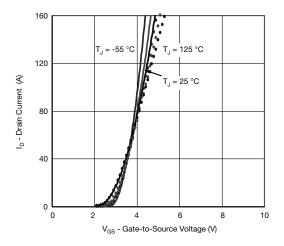
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

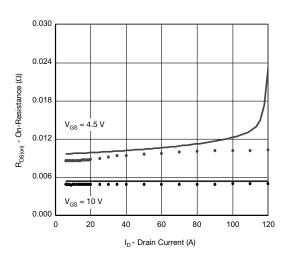
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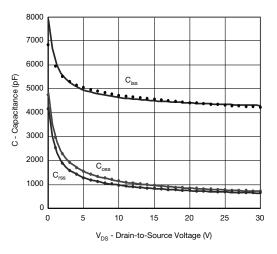
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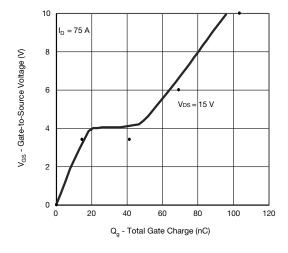
### COMPARISON OF MODEL WITH MEASURED DATA ( $T_J = 25~^{\circ}\text{C}$ , unless otherwise noted)

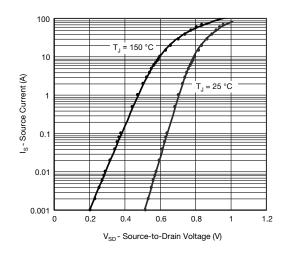












#### Note

Dots and squares represent measured data.
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